

FJYF2906

PNP Multi-Chip General Purpose Amplifier

- Collector-Emitter Voltage: V_{CEO} = 40V
 Amplifier and Switching Application
- E2 is on pin 1



Absolute Maximum Ratings TA=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	40	V
V _{CBO}	Collector-Base Voltage	40	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current - Continuous	150	mA
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 ~ +150	°C

Electrical Characteristics T_A=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Characte	eristics	•	•		•	
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_{C} = 1MA, I_{B} = 0$	40			V
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = 10 \mu A, I_E = 0$	40			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	5			V
I _{CEX}	Collector Cut-off Current	V _{CE} = 30V, V _{BE} = 3V			50	NА
On Characte	eristics	•		•		
h _{FE}	DC Current Gain *	$V_{CE} = 1V$, $I_{C} = 0.1$ MA $V_{CE} = 1V$, $I_{C} = 1$ mA $V_{CE} = 1V$, $I_{C} = 10$ mA $V_{CE} = 1V$, $I_{C} = 50$ mA $V_{CE} = 1V$, $I_{C} = 100$ mA	60 80 100 60 30		300	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 10$ mA, $I_B = 1$ mA $I_C = 50$ mA, $I_B = 5$ mA			0.3 0.5	V V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C = 10mA, I _B = 1mA I _C = 50mA, I _B = 5mA	0.65		0.95 1	V V
Small Signa	l Characteristics	•	•		•	
f _T	Current gain Bandwidth Product	V _{CE} = 20V, I _C = 10mA 250 f = 100MHz			MHz	
C _{obo}	Output Capacitance	V _{CB} = 5V, I _E = 0, f = 1MHz			4.5	pF
C _{ibo}	Input Capacitance	$V_{EB} = 0.5V, I_{C} = 0, f = 1MHz$			10	pF

^{*} Pulse Test: Pulse Width ≤ 300ms, Duty Cycle ≤ 2.0%

NOTE: All voltage (V) and currents (A) are negative for PNP transistors.

Thermal Characteristics T _A =25°C unless otherwise noted			
Symbol	Parameter	FJYF2906	Units
P _D	Total Device Dissipation	150	mW
_	Derate above 25°C	1.2	mW/°C
$R_{ heta JA}$	Thermal Resistance, Junction to Ambient	833	°C/W

Typical Characteristics

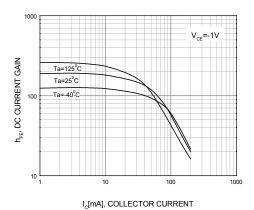


Figure 1. DC current Gain

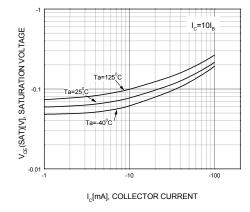


Figure 2. Collector-Emitter Saturation Voltage

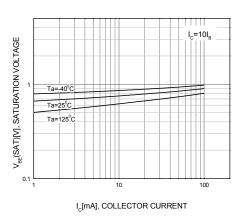


Figure 3. Base-Emitter Saturation Voltage

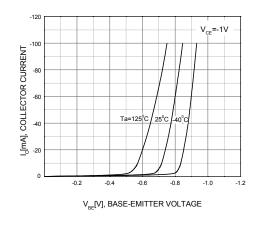


Figure 4. Base-Emitter On Voltage

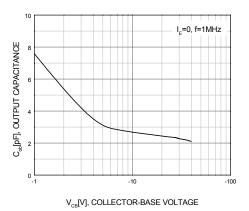
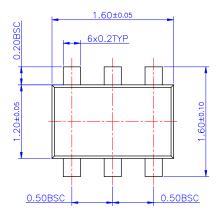


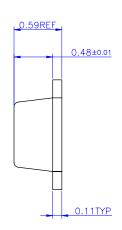
Figure 5. Collector Output Capacitance

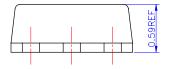
©2002 Fairchild Semiconductor Corporation Rev. A1, September 2002

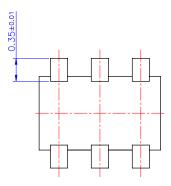
Package Dimensions

SOT-563F









Dimensions in Millimeters

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACEx™	FACT™	ImpliedDisconnect™	PACMAN™	SPM™
ActiveArray™	FACT Quiet series™	ISOPLANAR™	POP™	Stealth™
Bottomless™	FAST [®]	LittleFET™	Power247™	SuperSOT™-3
CoolFET™	FASTr™	MicroFET™	PowerTrench [®]	SuperSOT™-6
$CROSSVOLT^{\text{TM}}$	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOME™	GlobalOptoisolator™	MICROWIRE™	QS™	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E ² CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I ² C™	OCX™	RapidConfigure™	UHC™ _
Across the board. Around the world.™		OCXPro™	RapidConnect™	UltraFET [®]
The Power Franchise™		OPTOLOGIC [®]	SILENT SWITCHER®	VCX™
Programmable Active Droop™		OPTOPLANAR™	SMART START™	

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

©2002 Fairchild Semiconductor Corporation Rev. I1